

MOS FIELD EFFECT TRANSISTOR 2SK2487

SWITCHING N-CHANNEL POWER MOS FET

DESCRIPTION

The 2SK2487 is N-Channel MOS Field Effect Transistors designed for high voltage switching applications.

FEATURES

- Low on-state resistance RDS (on) = 1.6 Ω MAX. (VGS = 10 V, ID = 4.0 A)
- Low input capacitance $C_{iss} = 2 100 pF TYP.$
- · High Avalanche Capability Ratings

ABSOLUTE MAXIMUM RATINGS $(T_A = 25 \degree C)$

Drain to Source Voltage (Vgs = 0 V)	VDSS	900	V
Gate to Source Voltage (Vps = 0 V)	Vgss	±30	V
Drain Current (DC)	ID (DC)	±8.0	Α
Drain Current (pulse)*	D (pulse)	±20	Α
Total Power Dissipation (Tc = 25 °C)	P _{T1}	140	W
Total Power Dissipation (T _A = 25 °C)	P _{T2}	3.0	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	-55 to +150	°C
Single Avalanche Current**	las	8.0	Α
Single Avalanche Energy**	Eas	264	mJ

^{*} PW \leq 10 μ s, Duty Cycle \leq 1 %

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^{**} Starting T_{ch} = 25 °C, R_G = 25 Ω , V_{GS} = 20 V \rightarrow 0

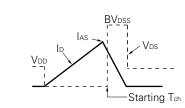


ELECTRICAL CHARACTERISTICS (TA = 25 °C)

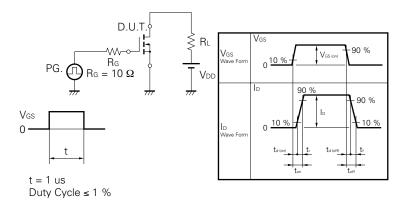
CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Drain to Source On-Resistance	RDS (on)		1.1	1.6	Ω	Vgs = 10 V, ID = 4.0 A
Gate to Source Cutoff Voltage	VGS (off)	2.5		3.5	V	V _{DS} = 10 V, I _D = 1 mA
Forward Transfer Admittance	yfs	3.0			S	V _{DS} = 20 V, I _D = 4.0 A
Drain Leakage Current	IDSS			100	μΑ	V _{DS} = V _{DSS} , V _{GS} = 0
Gate to Source Leakage Current	Igss			±100	nA	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0$
Input Capacitance	Ciss		2 100		pF	V _{DS} = 10 V
Output Capacitance	Coss		310		pF	V _G S = 0
Reverse Transfer Capacitance	Crss		60		pF	f = 1 MHz
Turn-On Delay Time	td (on)		30		ns	ID = 4.0 A
Rise Time	tr		20		ns	Vgs = 10 V
Turn-Off Delay Time	td (off)		130		ns	V _{DD} = 150 V
Fall Time	t _f		23		ns	$R_G = 10 \Omega$
Total Gate Charge	Q _G		65		nC	ID = 8.0 A
Gate to Source Charge	Qgs		11		nC	V _{DD} = 450 V
Gate to Drain Charge	Q _{GD}		29		nC	V _G S = 10 V
Body Diode Forward Voltage	VF (S-D)		1.0		V	IF = 8.0 A, VGS = 0
Reverse Recovery Time	trr		770		ns	IF = 8.0 A, VGS = 0
Reverse Recovery Charge	Qrr		5.0		μC	di/dt = 50 A/μs

Test Circuit 1 Avalanche Capability

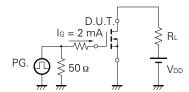
$R_{G} = 25 \Omega$ $V_{GS} = 20 - 0 V$ V_{DD} V_{DD}



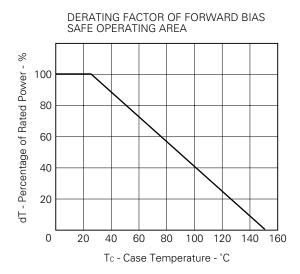
Test Circuit 2 Switching Time

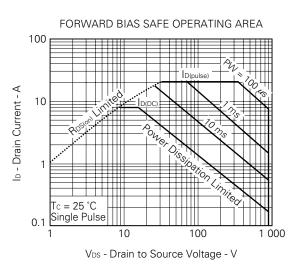


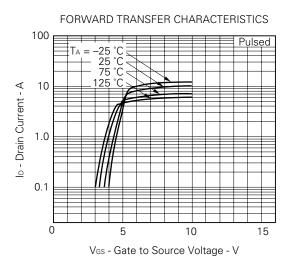
Test Circuit 3 Gate Charge

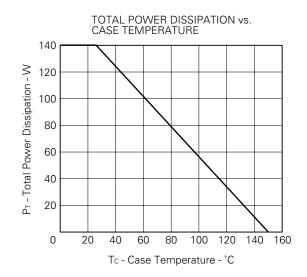


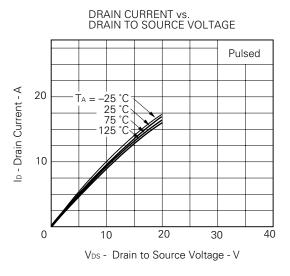
TYPICAL CHARACTERISTICS (TA = 25 °C)



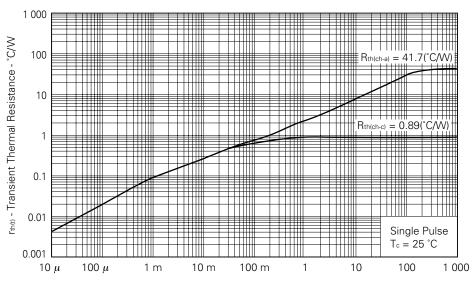






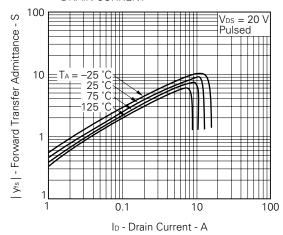


TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

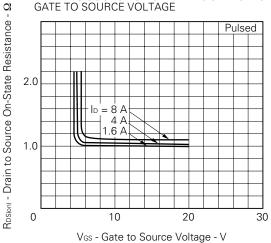


PW - Pulse Width - s

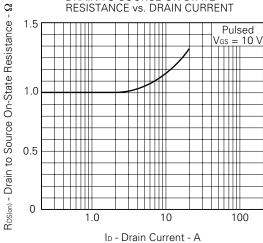
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



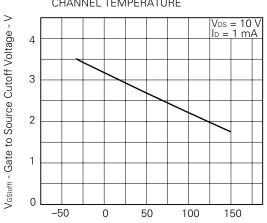
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



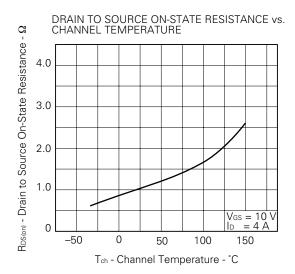


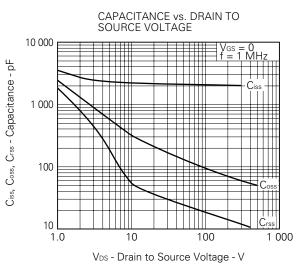


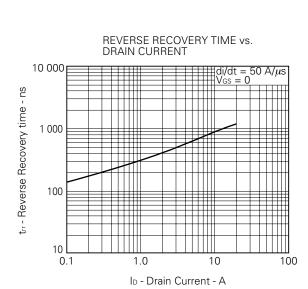
GATE TO SOURCE CUTOFF VOLTAGE vs. CHANNEL TEMPERATURE

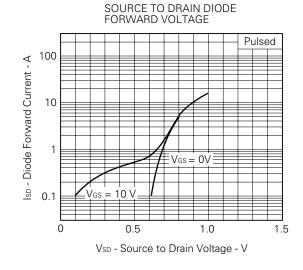


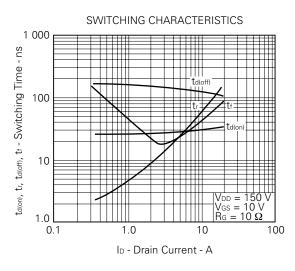
Tch - Channel Temperature - °C

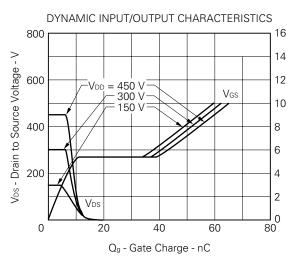


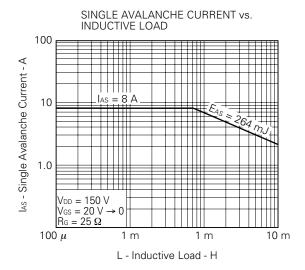


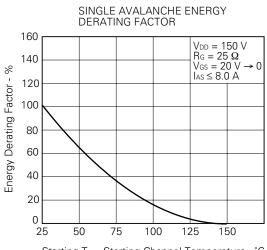








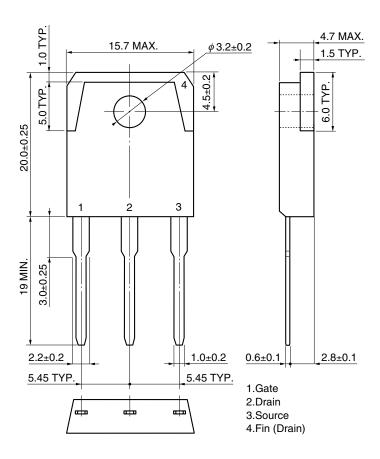




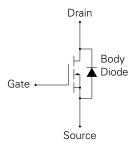
Starting T $_{\text{ch}}$ - Starting Channel Temperature - $^{\circ}\text{C}$

PACKAGE DRAWING (Unit: mm)

<R> TO-3P (MP-88)



EQUIVALENT CIRCUIT



Remark Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.

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